

1N4728A - 1N4758A Zener Diodes

Tolerance = 5%



DO-41 Glass case
COLOR BAND DENOTES CATHODE

Absolute Maximum Ratings * Ta = 25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|-----------------------------------|--|-------------|-------|
| P _D | Power Dissipation @ TL ≤ 50°C, Lead Length = 3/8" | 1.0 | W |
| | Derate above 50°C | 6.67 | mW/°C |
| T _J , T _{STG} | Operating and Storage Temperature Range | -65 to +200 | °C |

^{*} These ratings are limiting values above which the serviceability of the diode may be impaired.

Electrical Characteristics T_a = 25°C unless otherwise noted

| Device | V _Z (V) @ I _Z (Note 1) | | | Test Current | Max. Zener Impedance | | | Leakage Current | | Non-Repetitive Peak Reverse | |
|-------------------------------|--|-------------------|------------------------|---------------------|---------------------------------------|--|-------------------------|---------------------------------|-----------------------|--|--|
| | Min. | Тур. | Max. | I _Z (mA) | Z _Z @Ι _Z (Ω) | Z _{ZK} @ I _{ZK} (Ω) | I _{ZK} (mA) | Ι _R (μ A) | V _R (V) | Current I _{ZSM} (mA) (Note 2) | |
| 1N4728A 1N4729A | 3.135 3.42 | 3.3 3.6 | 3.465 3.78 | 76 69 | 10 10 | 400 400 | 1 | 100 100 | 1 | 1380 1260 | |
| 1N4730A 1N4731A | 3.705 4.085 | 3.9 4.3 | 4.095 4.515 | 64 58 53 | 9 9 8 | 400 400 | 1 | 50 10 10 | 1 | 1190 1070 | |
| 1N4732A 1N4733A 1N4734A | 4.465 4.845 5.32 | 4.7 5.1 5.6 | 4.935 5.355 5.88 | 49 45 | 7 5 | 500 550 600 | 1 | 10 | 1 2 | 970 890 810 | |
| 1N4734A 1N4735A 1N4736A | 5.89 6.46 | 6.2 6.8 | 6.51 7.14 | 45 41 37 | 2 3.5 | 700 700 | 1 | 10 10 10 | 3 4 | 730 660 | |
| 1N4737A 1N4738A | 7.125 7.79 | 7.5 8.2 | 7.875 8.61 | 34 31 | 4.5 | 700 700 | 0.5 | 10 10 | 5 6 | 605 550 | |
| 1N4739A 1N4740A | 8.645 9.5 | 9.1 10 | 9.555 10.5 | 28 25 | 5 7 | 700 700 | 0.5 0.25 | 10 10 | 7 7.6 | 500 454 | |
| 1N4741A 1N4742A | 10.45 11.4 | 11 12 | 11.55 12.6 | 23 21 | 8 9 | 700 700 | 0.25 0.25 | 5 5 | 8.4 9.1 | 414 380 | |

| Device | V _Z (V) @ I _Z (Note 1) | | | Test Current | Max. Zener Impedance | | | Leakage Current | | Non-Repetitive Peak Reverse |
|---|--|----------------------------|--|---------------------------|----------------------------|---|--------------------------------------|---------------------------------|--------------------------------------|--|
| | Min. | Тур. | Max. | I _Z (mA) | Z z@Iz (Ω) | Z_{ZK} @ I_{ZK} (Ω) | I _{ZK} (mA) | Ι _R (μ A) | V _R (V) | Current I _{ZSM} (mA) (Note 2) |
| 1N4743A | 12.35 | 13 | 13.65 | 19 | 10 | 700 | 0.25 | 5 | 9.9 | 344 |
| 1N4744A | 14.25 | 15 | 15.75 | 17 | 14 | 700 | 0.25 | 5 | 11.4 | 304 |
| 1N4745A | 15.2 | 16 | 16.8 | 15.5 | 16 | 700 | 0.25 | 5 | 12.2 | 285 |
| 1N4746A | 17.1 | 18 | 18.9 | 14 | 20 | 750 | 0.25 | 5 | 13.7 | 250 |
| 1N4747A | 19 | 20 | 21 | 12.5 | 22 | 750 | 0.25 | 5 | 15.2 | 225 |
| 1N4748A 1N4749A | 20.9 22.8 | 22 24 | 23.1 25.2 | 11.5 10.5 | 23 25 | 750 750 | 0.25 0.25 | 5 5 | 16.7 18.2 | 205 190 |
| 1N4750A | 25.65 | 27 | 28.35 | 9.5 | 35 | 750 | 0.25 | 5 | 20.6 | 170 |
| 1N4751A 1N4752A | 28.5 31.35 | 30 33 | 31.5 34.65 | 8.5 7.5 | 40 45 | 1000 1000 | 0.25 0.25 | 5 5 | 22.8 25.1 | 150 135 |
| 1N4753A 1N4754A 1N4755A 1N4756A 1N4757A | 34.2 37.05 40.85 44.65 48.45 | 36 39 43 47 51 | 37.8 40.95 45.15 49.35 53.55 | 7 6.5 6 5.5 5 | 50 60 70 80 95 | 1000 1000 1500 1500 1500 | 0.25 0.25 0.25 0.25 0.25 | 5 5 5 5 5 | 27.4 29.7 32.7 35.8 38.8 | 125 115 110 95 90 |
| 1N4758A | 53.2 | 56 | 58.8 | 4.5 | 110 | 2000 | 0.25 | 5 | 42.6 | 80 |

Notes:

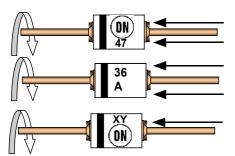
1. Zener Voltage (V_Z) The zener voltage is measured with the device junction in the thermal equilibrium at the lead temperature (T_L) at 30°C \pm 1°C and 3/8" lead length.

Top Mark Information

| Device | Line 1 | Line 2 | Line 3 | Line 4 | Line 5 |
|---------|--------|--------|--------|--------|--------|
| 1N4728A | LOGO | 47 | 28 | Α | XY |
| 1N4729A | LOGO | 47 | 29 | Α | XY |
| 1N4730A | LOGO | 47 | 30 | Α | XY |
| 1N4731A | LOGO | 47 | 31 | Α | XY |
| 1N4732A | LOGO | 47 | 32 | Α | XY |
| 1N4733A | LOGO | 47 | 33 | Α | XY |
| 1N4734A | LOGO | 47 | 34 | Α | XY |
| 1N4735A | LOGO | 47 | 35 | Α | XY |
| 1N4736A | LOGO | 47 | 36 | Α | XY |
| 1N4737A | LOGO | 47 | 37 | Α | XY |
| 1N4738A | LOGO | 47 | 38 | Α | XY |
| 1N4739A | LOGO | 47 | 39 | Α | XY |
| 1N4740A | LOGO | 47 | 40 | Α | XY |
| 1N4741A | LOGO | 47 | 41 | Α | XY |
| 1N4742A | LOGO | 47 | 42 | Α | XY |
| 1N4743A | LOGO | 47 | 43 | Α | XY |
| 1N4744A | LOGO | 47 | 44 | Α | XY |
| 1N4745A | LOGO | 47 | 45 | Α | XY |
| 1N4746A | LOGO | 47 | 46 | Α | XY |
| 1N4747A | LOGO | 47 | 47 | Α | XY |
| 1N4748A | LOGO | 47 | 48 | Α | XY |
| 1N4749A | LOGO | 47 | 49 | Α | XY |
| 1N4750A | LOGO | 47 | 50 | Α | XY |
| 1N4751A | LOGO | 47 | 51 | Α | XY |
| 1N4752A | LOGO | 47 | 52 | Α | XY |
| 1N4753A | LOGO | 47 | 53 | Α | XY |
| 1N4754A | LOGO | 47 | 54 | Α | XY |
| 1N4755A | LOGO | 47 | 55 | Α | XY |
| 1N4756A | LOGO | 47 | 56 | Α | XY |
| 1N4757A | LOGO | 47 | 57 | Α | XY |
| 1N4758A | LOGO | 47 | 58 | Α | XY |

^{2. 2} Square wave Reverse Surge at 8.3 msec soak time.

Top Mark Information (Continued)



1st line: F - ON Semiconductor Logo

 2^{nd} line: Device Name - 3^{rd} to 4^{th} characters of device name for 1Nxx series

or 4th to 6th characters for BZXyy series

 3^{rd} line: Device Name - 5^{th} to 6^{th} characters of device name for 1Nxx series or Voltage rating for BZXyy series

4th line: Device Name - 7th to 8th characters of device name for 1Nxx series or Large Die identification only for BZXyy series

5th line: Date Code - Two Digit - Six Weeks Date Code

General Requirements:

1.0 Cathode Band

2.0 First Line: (DN) - ON Semiconductor Logo

3.0 Second Line: Device name - For 1Nxx series: 3rd to 4th characters of the device name.

For BZxx series: 4th to 6th characters of the device name.

4.0 Third Line: Device name - For 1Nxx series: 5th to 6th characters of the device name. For BZXyy series: Voltage rating

5.0 Third Line: Device name - For 1Nxx series: 7th to 8th characters of the device name.

(the 8th character is the large die identification)

For BZXyy series: Large Die Identification character

6.0 Fourth Line: Date Code - Two Digit - Six Weeks Date Code

Where: X represents the last digit of the calendar year

Y represents the Six weeks numeric code

7.0 Devices shall be marked as required in the device specification (PID or ON Semiconductor Test Spec).

8.0 Maximum no. of marking lines: 5

9.0 Maximum no. of digits per line: 3

10.0 ON Semiconductor logo must be 20 % taller than the alphanumeric marking and should occupy the 2 characters of the specified line. 11.0 Marking Font: Arial (Except ON Semiconductor Logo)

12.0 First character of each marking line must be aligned vertically.

13.0 All device markings must be based on ON Semiconductor device specification.

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